

#### **Features**

- High Dense Cell Design for Extremely Low R<sub>DS(ON)</sub>
- · Voltage Controlled Small Signal Switch
- · Surface Mount Package
- · Epoxy Meets UL 94 V-0 Flammability Rating
- · Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

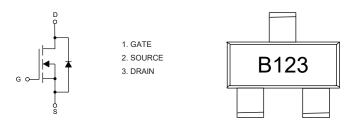
## **Maximum Ratings**

- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature: -55°C to +150°C
- Thermal Resistance: 625°C/W Junction to Ambient

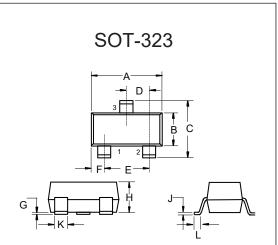
Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V <sub>DS</sub>	100	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	0.17	Α
Power Dissipation	P <sub>D</sub>	0.20	W

Note: 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

## **Internal Structure and Marking Code**

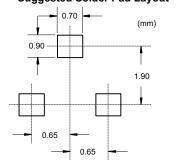


# **N-Channel MOSFET**



DIMENSIONS						
DIM	INCHES		MM		NOTE	
DIIVI	MIN	MAX	MIN	MAX	NOTE	
Α	0.071	0.087	1.80	2.20		
В	0.045	0.053	1.15	1.35		
С	0.083	0.096	2.10	2.45		
D	0.026		0.65		TYP.	
Е	0.047	0.055	1.20	1.40		
F	0.012	0.016	0.30	0.40		
G	0.000	0.004	0.00	0.10		
Н	0.035	0.044	0.90	1.10		
J	0.002	0.010	0.05	0.25		
K	0.006	0.016	0.15	0.40		
L	0.010	0.018	0.26	0.46		

### Suggested Solder Pad Layout





## **ELECTRICAL CHARACTERISTICS (Ta=25℃ unless otherwise specified)**

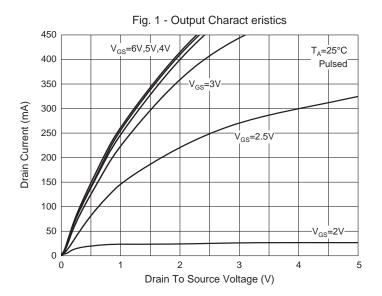
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Static Characteristics	1					
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	100			V
Gate-Threshold Voltage <sup>(Note2)</sup>	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_D=250\mu A$	1.0		2.8	V
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =± 20V, V <sub>DS</sub> =0V			±50	nA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V, V <sub>GS</sub> =0V V <sub>DS</sub> =20V, V <sub>GS</sub> =0V			1 10	μA nA
Drain-Source On-Resistance <sup>(Note2)</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =0.17A V <sub>GS</sub> =4.5V, I <sub>D</sub> =0.17A			6	Ω
Forward Transconductance <sup>(Note2)</sup>	g <sub>FS</sub>	V <sub>DS</sub> =10V, I <sub>D</sub> =0.17A	80		10	mS
Diode Forward Voltage <sup>(Note2)</sup>	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =0.34A			1.3	V
Dynamic Characteristics(Note4)	•		-			
Input Capacitance	C <sub>iss</sub>			29	60	pF
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =25V,V <sub>GS</sub> =0V, f=1MHz		10	15	
Reverse Transfer Capacitance	C <sub>rss</sub>			2	6	
Switching Characteristics	1					
Total Gate Charge	Qg			1.4	2	
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =10V,V <sub>GS</sub> =10V,I <sub>D</sub> =0.22A		0.15	0.25	nC
Gate-Drain Charge	$Q_{gd}$			0.2	0.4	
Turn-On Delay Time <sup>(Note3,4)</sup>	t <sub>d(on)</sub>				8	
Turn-On Rise Time <sup>(Note3,4)</sup>	t <sub>r</sub>	$V_{DD}$ =30V, $V_{GS}$ =10V, $R_{G}$ =50 $\Omega$ ,			8	
Turn-Off Delay Time <sup>(Note3,4)</sup>	t <sub>d(off)</sub>	I <sub>D</sub> =0.28A			13	- ns
Turn-Off Fall Time <sup>(Note3,4)</sup>	t <sub>f</sub>				16	

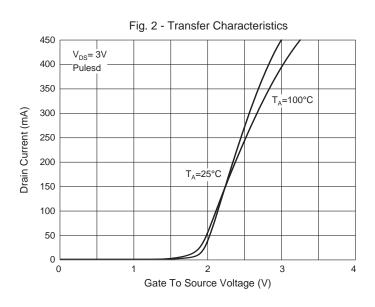
## Note:

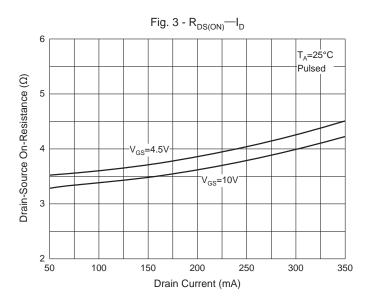
- 2. Surface Mounted on FR4 Board Using the Minimum Recommended Pad Size.
- 3.Pulse Test : Pulse Width=300µs, Duty Cycle≤2%.
- 4. Switching Characteristics are Independent of Operating Junction Temperature.
- 5. Graranted by Design, Not Subject to Producting.

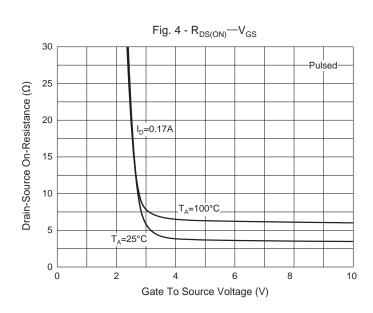


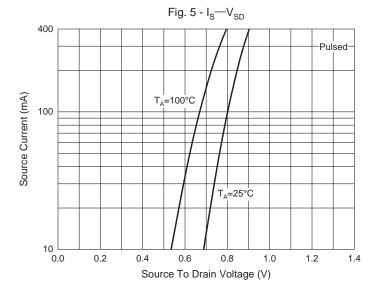
#### **Curve Characteristics**

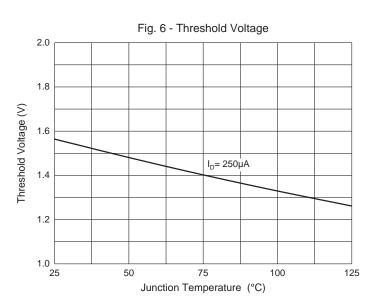














### **Ordering Information**

Device	Packing	
Part Number-TP	Tape&Reel:3Kpcs/Reel	

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